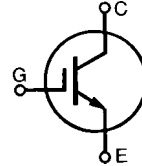


IGBT

IXSH 35N120B
IXST 35N120B

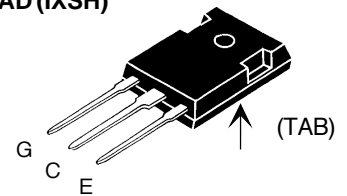
$I_{C25} = 70 \text{ A}$
 $V_{CES} = 1200 \text{ V}$
 $V_{CE(sat)} = 3.6 \text{ V}$

"S" Series - Improved SCSOA Capability

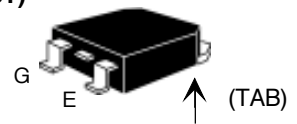


Symbol	Test Conditions	Maximum Ratings
V_{CES}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	1200 V
V_{CGR}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$	1200 V
V_{GES}	Continuous	± 20 V
V_{GEM}	Transient	± 30 V
I_{C25}	$T_C = 25^\circ\text{C}$	70 A
I_{C90}	$T_C = 90^\circ\text{C}$	35 A
I_{CM}	$T_C = 25^\circ\text{C}, 1 \text{ ms}$	140 A
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}, T_J = 125^\circ\text{C}, R_G = 5 \Omega$ Clamped inductive load	$I_{CM} = 90$ @ $0.8 V_{CES}$ A
t_{sc}	$T_J = 125^\circ\text{C}, V_{CE} = 720 \text{ V}; V_{GE} = 15 \text{ V}, R_G = 22 \Omega$	10 μs
P_C	$T_C = 25^\circ\text{C}$	300 W
T_J		-55 ... +150 $^\circ\text{C}$
T_{JM}		150 $^\circ\text{C}$
T_{stg}		-55 ... +150 $^\circ\text{C}$
M_d	Mounting torque (TO-247)	1.13/10 Nm/lb.in.
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300 $^\circ\text{C}$
Weight	TO-247	6 g
	TO-268	4 g

TO-247 AD (IXSH)



TO-268 (IXST)



G = Gate
E = Emitter

C = Collector
TAB = Collector

Features

- Epitaxial Silicon drift region
 - fast switching
 - small tail current
- MOS gate turn-on for drive simplicity

Applications

- AC motor speed control
- DC servo and robot drives
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- DC choppers

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
BV_{CES}	$I_C = 1.0 \text{ mA}, V_{GE} = 0 \text{ V}$	1200		V
$V_{GE(th)}$	$I_C = 250 \mu\text{A}, V_{CE} = V_{GE}$	3		6 V
I_{CES}	$V_{CE} = 0.8 V_{CES}$ Note 1	$T_J = 25^\circ\text{C}$		50 μA
		$T_J = 125^\circ\text{C}$		2.5 mA
I_{GES}	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			± 100 nA
$V_{CE(sat)}$	$I_C = I_{C90}, V_{GE} = 15 \text{ V}$ Note 2	$T_J = 25^\circ\text{C}$		3.6 V
		$T_J = 125^\circ\text{C}$		2.9 V

